

# DATA SHEET

# NEC

## NPN SILICON RF TWIN TRANSISTOR

# ∞PA895TS

### NPN SILICON RF TRANSISTOR (WITH 2 ELEMENTS) IN A 6-PIN SUPER LEAD-LESS MINIMOLD

#### FEATURES

- Built-in low voltage operation, low phase distortion transistor suited for OSC applications  
 $f_T = 4.5 \text{ GHz TYP.}$ ,  $|S_{21e}|^2 = 4.0 \text{ dB TYP. @ } V_{CE} = 1 \text{ V, } I_c = 5 \text{ mA, } f = 2 \text{ GHz}$
- Built-in 2 transistors (2 · 2SC5800)
- 6-pin super lead-less minimold package

#### BUILT-IN TRANSISTORS

	Q1, Q2
Flat-lead 3-pin thin-type ultra super minimold part No.	2SC5800

#### ORDERING INFORMATION

Part Number	Quantity	Supplying Form
∞PA895TS	50 pcs (Non reel)	• 8 mm wide embossed taping
∞PA895TS-T3	10 kpcs/reel	• Pin 1 (Q1 Collector), Pin 6 (Q1 Base) face the perforation side of the tape

**Remark** To order evaluation samples, contact your nearby sales office.  
The unit sample quantity is 50 pcs.

**Caution** Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = +25°C)**

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V <sub>CB0</sub>	9	V
Collector to Emitter Voltage	V <sub>CEO</sub>	5.5	V
Emitter to Base Voltage	V <sub>EBO</sub>	1.5	V
Collector Current	I <sub>c</sub>	100	mA
Total Power Dissipation	P <sub>tot</sub> <sup>Note</sup>	110 in 1 element	mW
		130 in 2 elements	
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-65 to +150	°C

**Note** Mounted on 1.08 cm<sup>2</sup> · 1.0 mm (t) glass epoxy PCB

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = +25°C)**

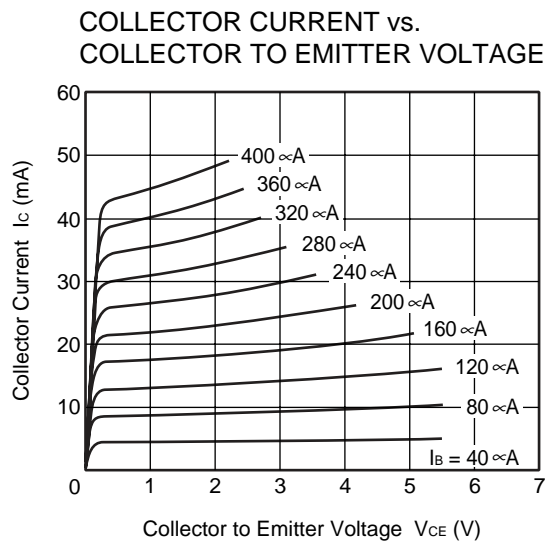
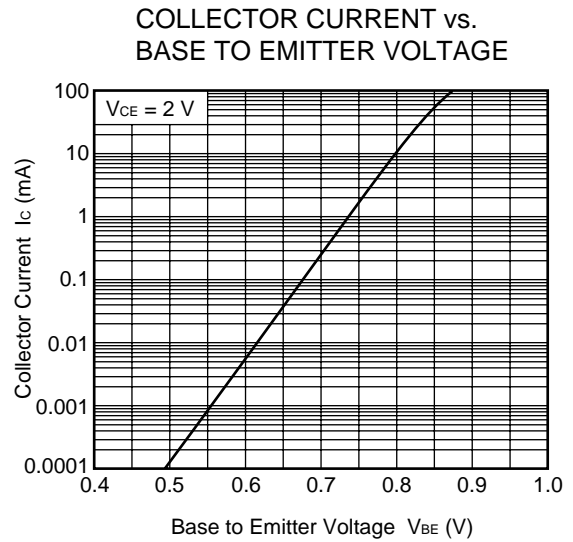
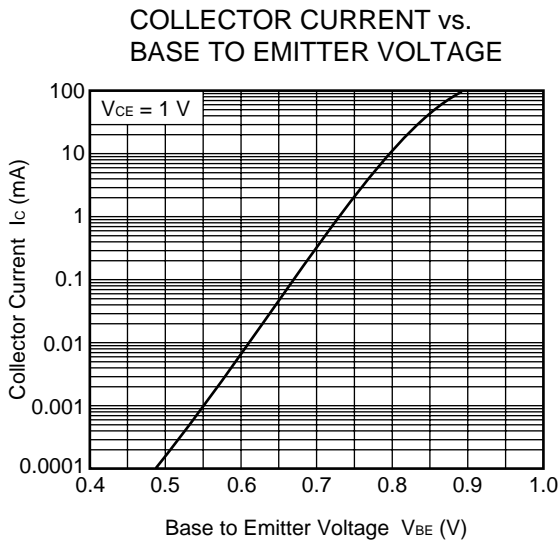
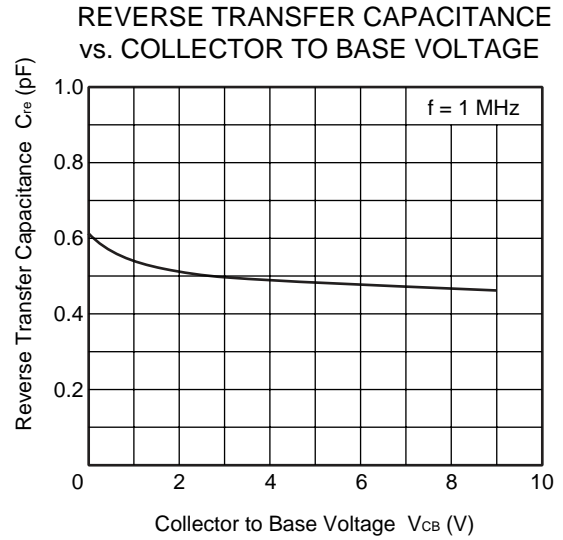
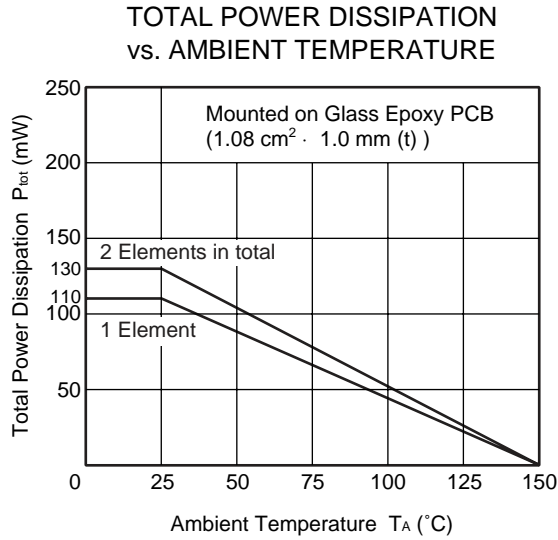
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Collector Cut-off Current	I <sub>CB0</sub>	V <sub>CB</sub> = 5 V, I <sub>E</sub> = 0 mA	-	-	600	nA
Emitter Cut-off Current	I <sub>EBO</sub>	V <sub>EB</sub> = 1 V, I <sub>c</sub> = 0 mA	-	-	600	nA
DC Current Gain	h <sub>FE</sub> <sup>Note 1</sup>	V <sub>CE</sub> = 1 V, I <sub>c</sub> = 5 mA	100	120	145	-
Gain Bandwidth Product (1)	f <sub>T</sub>	V <sub>CE</sub> = 1 V, I <sub>c</sub> = 5 mA, f = 2 GHz	3.0	4.5	-	GHz
Gain Bandwidth Product (2)	f <sub>T</sub>	V <sub>CE</sub> = 1 V, I <sub>c</sub> = 15 mA, f = 2 GHz	5.0	6.5	-	GHz
Insertion Power Gain (1)	S <sub>21e</sub>   <sup>2</sup>	V <sub>CE</sub> = 1 V, I <sub>c</sub> = 5 mA, f = 2 GHz	3.0	4.0	-	dB
Insertion Power Gain (2)	S <sub>21e</sub>   <sup>2</sup>	V <sub>CE</sub> = 1 V, I <sub>c</sub> = 15 mA, f = 2 GHz	4.5	5.5	-	dB
Noise Figure	NF	V <sub>CE</sub> = 1 V, I <sub>c</sub> = 10 mA, f = 2 GHz, Z <sub>S</sub> = Z <sub>opt</sub>	-	1.9	2.5	dB
Reverse Transfer Capacitance	C <sub>re</sub> <sup>Note 2</sup>	V <sub>CB</sub> = 0.5 V, I <sub>E</sub> = 0 mA, f = 1 MHz	-	0.6	0.8	pF

- Notes** 1. Pulse measurement: PW ≤ 350 ns, Duty Cycle ≤ 2%  
 2. Collector to base capacitance when the emitter grounded

**h<sub>FE</sub> CLASSIFICATION**

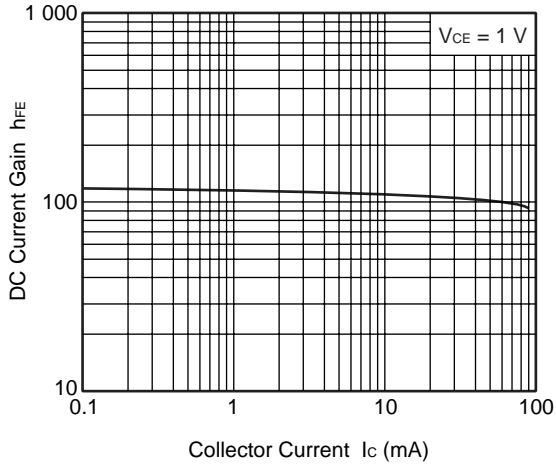
Rank	FB
Marking	kP
h <sub>FE</sub> Value	100 to 145

★ TYPICAL CHARACTERISTICS (T<sub>A</sub> = +25°C, unless otherwise specified)

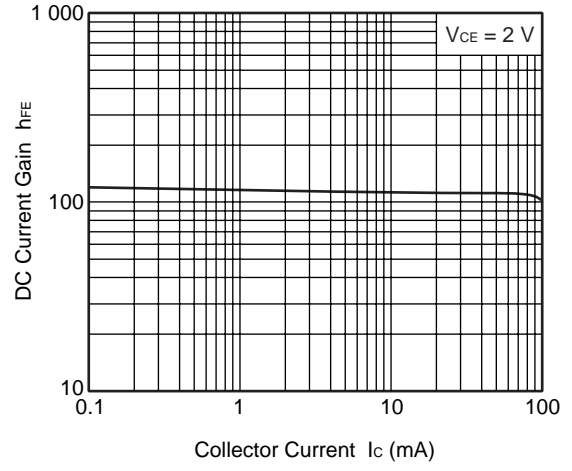


**Remark** The graphs indicate nominal characteristics.

DC CURRENT GAIN vs.  
COLLECTOR CURRENT



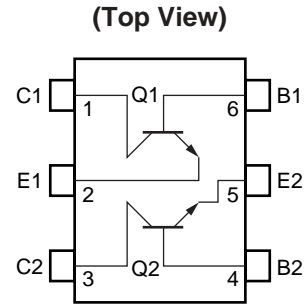
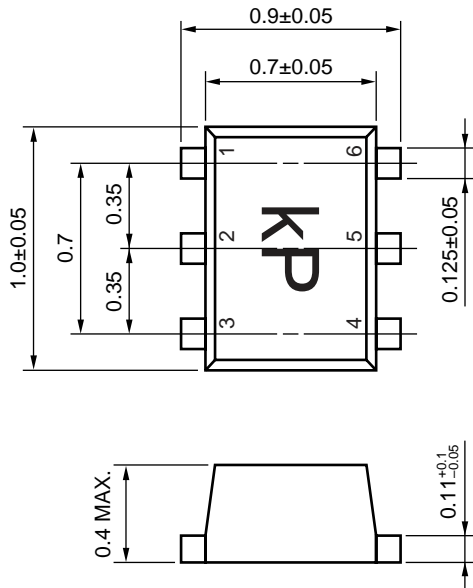
DC CURRENT GAIN vs.  
COLLECTOR CURRENT



**Remark** The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN SUPER LEAD-LESS MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. Collector (Q1)
- 2. Emitter (Q1)
- 3. Collector (Q2)
- 4. Base (Q2)
- 5. Emitter (Q2)
- 6. Base (Q1)

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